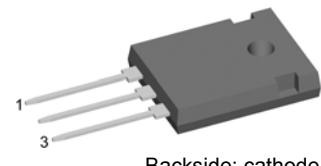
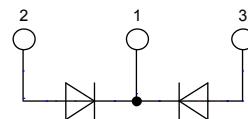


## Sonic Fast Recovery Diode

High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Common Cathode

### Part number

DHG 40 C 1200 HB



Backside: cathode

### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package:

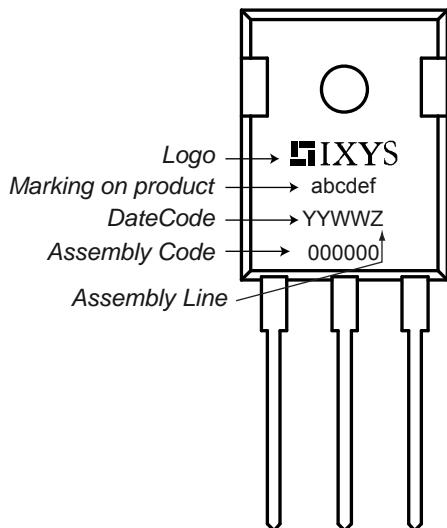
- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Symbol	Definition	Conditions		Ratings		
				min.	typ.	max.
$V_{RRM}$	max. repetitive reverse voltage		$T_{VJ} = 25^\circ\text{C}$			1200 V
$I_R$	reverse current	$V_R = 1200\text{ V}$	$T_{VJ} = 25^\circ\text{C}$		25 $\mu\text{A}$	
		$V_R = 1200\text{ V}$	$T_{VJ} = 125^\circ\text{C}$		0.4 mA	
$V_F$	forward voltage	$I_F = 20\text{ A}$	$T_{VJ} = 25^\circ\text{C}$		2.24 V	
		$I_F = 40\text{ A}$			2.89 V	
		$I_F = 20\text{ A}$	$T_{VJ} = 125^\circ\text{C}$		2.24 V	
		$I_F = 40\text{ A}$			3.15 V	
$I_{FAV}$	average forward current	rectangular	$d = 0.5$	$T_c = 95^\circ\text{C}$		20 A
$V_{FO}$ $r_F$	threshold voltage slope resistance } for power loss calculation only			$T_{VJ} = 150^\circ\text{C}$		1.29 V
					43 mΩ	
$R_{thJC}$	thermal resistance junction to case				0.90 K/W	
$T_{VJ}$	virtual junction temperature			-55	150	$^\circ\text{C}$
$P_{tot}$	total power dissipation				140 W	
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}$ (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		150 A
$I_{RM}$	max. reverse recovery current			$T_{VJ} = 25^\circ\text{C}$	15	A
		$I_F = 20\text{ A}; V_R = 600\text{ V}$		$T_{VJ} = 125^\circ\text{C}$	20	A
		$-di_F/dt = 400\text{ A}/\mu\text{s}$		$T_{VJ} = 25^\circ\text{C}$	200 ns	
$t_{rr}$	reverse recovery time			$T_{VJ} = 125^\circ\text{C}$	350 ns	
$C_J$	junction capacitance	$V_R = 600\text{ V}; f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$	8 pF	

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	RMS current	per terminal <sup>1)</sup>			70	A
$R_{thC}$	thermal resistance case to heatsink			0.25		K/W
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				6		g
$M_D$	mounting torque		0.8		1.2	Nm
$F_c$	mounting force with clip		20		120	N

<sup>1)</sup>  $I_{RMS}$  is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2).  
In case of (1) and a common cathode/anode configuration with a non-isolated backside,  
the current capability can be increased by connecting the backside.

### Product Marking

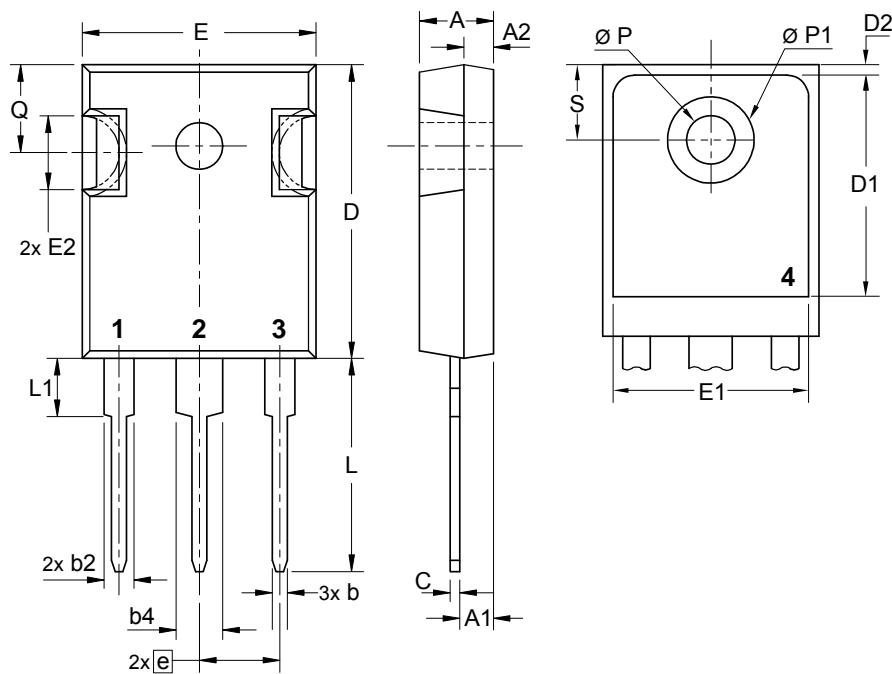


### Part number

D = Diode  
 H = Sonic Fast Recovery Diode  
 G = extreme fast  
 40 = Current Rating [A]  
 C = Common Cathode  
 1200 = Reverse Voltage [V]  
 HB = TO-247AD (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG 40 C 1200 HB	DHG40C1200HB	Tube	30	505138

## Outlines TO-247



Sym.	Inches min.      max.	Millimeter min.      max.
A	0.185    0.209	4.70    5.30
A1	0.087    0.102	2.21    2.59
A2	0.059    0.098	1.50    2.49
D	0.819    0.845	20.79    21.45
E	0.610    0.640	15.48    16.24
E2	0.170    0.216	4.31    5.48
e	0.215 BSC	5.46 BSC
L	0.780    0.800	19.80    20.30
L1	-    0.177	-    4.49
Ø P	0.140    0.144	3.55    3.65
Q	0.212    0.244	5.38    6.19
S	0.242 BSC	6.14 BSC
b	0.039    0.055	0.99    1.40
b2	0.065    0.094	1.65    2.39
b4	0.102    0.135	2.59    3.43
c	0.015    0.035	0.38    0.89
D1	0.515    -	13.07    -
D2	0.020    0.053	0.51    1.35
E1	0.530    -	13.45    -
Ø P1	-    0.29	-    7.39

